

30A, 45V - 150V Schottky Barrier Rectifier

FEATURES

- Low power loss, high efficiency
- Guard ring for overvoltage protection
- High surge current capability
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converters

MECHANICAL DATA

- Case: TO-220AB
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Mounting torque: 0.56 N·m maximum
 Meet JESD 201 class 1A whisker test
- · Polarity: As marked
- Weight: 1.90g (approximately)

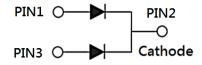
KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
I _F	30	Α		
V_{RRM}	45 - 150	V		
I _{FSM}	200	Α		
T_{JMAX}	150	°C		
Package	TO-220AB			
Configuration	Dual dies			







TO-220AB



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)							
		MBR	MBR	MBR	MBR	MBR	
PARAMETER	SYMBOL	3045	3060	3080	30100	30150	UNIT
		CT-Y	CT-Y	CT-Y	CT-Y	CT-Y	
Marking code on the device		MBR 3045CT	MBR 3060CT	MBR 3080CT	MBR 30100CT	MBR 30150CT	
Repetitive peak reverse voltage	V_{RRM}	45	60	80	100	150	V
Reverse voltage, total rms value	$V_{R(RMS)}$	31	42	56	70	105	V
Forward current	I _F	30				Α	
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}	200				А	
Peak repetitive reverse surge current ⁽¹⁾	I _{RRM}	1 0.5				А	
Peak repetitive forward current (Rated V _R , Square wave, 20KHz)	I _{FRM}	30				Α	
Critical rate of rise of off-state voltage	dv/dt	10,000				V/µs	
Junction temperature	TJ	-55 to +150				°C	
Storage temperature	T _{STG}	-55 to +150 °				°C	

Notes:

1. $tp = 2.0\mu s$, 1.0KHz

THERMAL PERFORMANCE				
PARAMETER		SYMBOL	TYP	UNIT
Junction-to-case thermal resistance	MBR3045CT-Y MBR3060CT-Y MBR3080CT-Y	R _{eJC}	1.0	°C/W
Junction-to-case thermal resistance	MBR30100CT-Y MBR30150CT-Y	R _{eJC}	1.5	°C/W

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
	MBR3045CT-Y	I _F = 15A, T _J = 25°C		•	0.70	V
	MBR3060CT-Y			1	0.77	V
	MBR3080CT-Y MBR30100CT-Y			-	0.84	V
	MBR30150CT-Y			-	0.95	V
	MBR3045CT-Y			-	0.82	V
	MBR3060CT-Y			-	-	V
	MBR3080CT-Y MBR30100CT-Y	I _F = 30A, T _J = 25°C		-	0.94	V
Forward voltage per	MBR30150CT-Y		V	-	1.02	V
diode ⁽¹⁾	MBR3045CT-Y	I _F = 15A, T _J = 125°C	V_{F}	-	0.60	V
	MBR3060CT-Y			-	0.67	V
	MBR3080CT-Y MBR30100CT-Y			-	0.70	V
	MBR30150CT-Y			-	0.92	V
	MBR3045CT-Y	I _F = 30A, T _J = 125°C		-	0.73	V
	MBR3060CT-Y			-	-	V
	MBR3080CT-Y MBR30100CT-Y			-	0.82	V
	MBR30150CT-Y			-	0.98	V
Reverse current @ rated V_R per diode ⁽²⁾	MBR3045CT-Y MBR3060CT-Y MBR3080CT-Y MBR30100CT-Y	T _J = 25°C		-	200	μA
	MBR30150CT-Y			-	100	μΑ
	MBR3045CT-Y	T _J = 125°C	I _R	-	40	mA
••••	MBR3060CT-Y			-	10	mA
	MBR3080CT-Y MBR30100CT-Y			-	7.5	mA
	MBR30150CT-Y			-	5	mA

Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

ORDERING INFORMATION					
ORDERING CODE ⁽¹⁾	PACKAGE	PACKING			
MBR30xCT-Y	TO-220AB	50 / Tube			

Notes:

1. "x" defines voltage from 45V(MBR3045CT-Y) to 150V(MBR30150CT-Y)



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.1 Forward Current Derating Curve

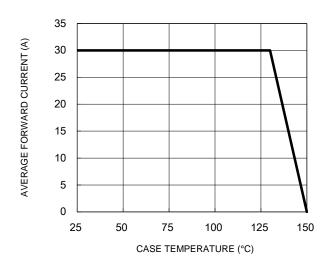


Fig.2 Typical Junction Capacitance

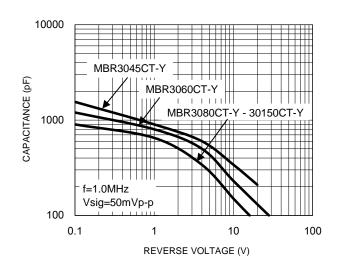
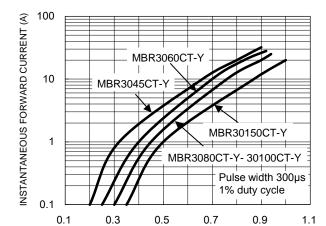


Fig.3 Typical Reverse Characteristics

Fig.4 Typical Forward Characteristics



FORWARD VOLTAGE (V)

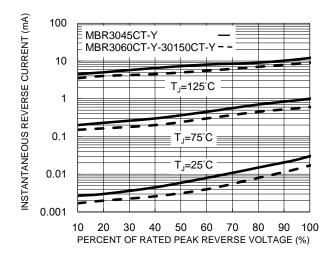
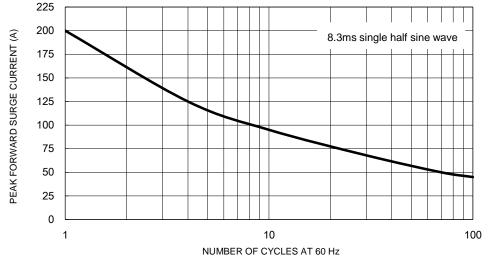


Fig.5 Maximum Non-Repetitive Forward Surge Current

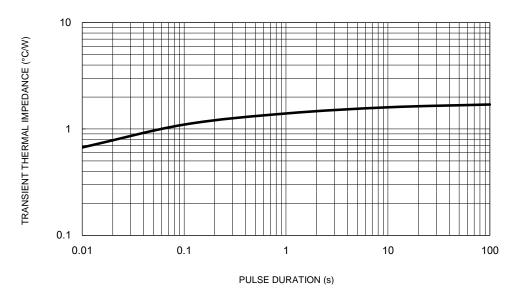


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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

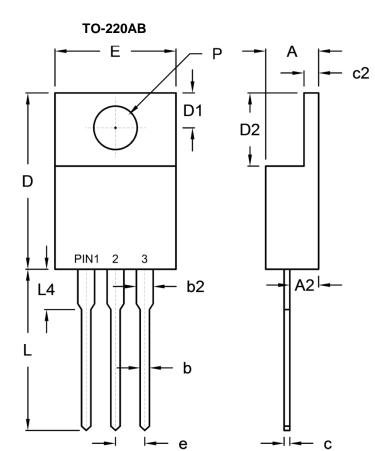
Fig.6 Typical Transient Thermal Impedance





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PACKAGE OUTLINE DIMENSIONS



DIM.	Unit	(mm)	Unit (inch)		
DIIVI.	Min.	Max.	Min.	Max.	
Α	4.42	4.76	0.174	0.187	
A2	2.20	2.80	0.087	0.110	
b	0.68	0.94	0.027	0.037	
b2	1.14	1.77	0.045	0.070	
С	0.35	0.64	0.014	0.025	
c2	1.14	1.40	0.045	0.055	
D	14.60	16.00	0.575	0.630	
D1	2.62	3.44	0.103	0.135	
D2	5.84	6.86	0.230	0.270	
E	-	10.50	-	0.413	
е	2.41	2.67	0.095	0.105	
L	13.19	14.79	0.519	0.582	
L4	2.80	4.20	0.110	0.165	
Р	3.54	4.00	0.139	0.157	

MARKING DIAGRAM



P/N = Marking Code G = Green Compound

YWW = Date Code F = Factory Code

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